Diode Semiconductor Device - Page 1 of 1



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Inclosure Ma	terial:
Glass	
Overall Leng	th:
0.300 inches	
Terminal Len	aath:
1.000 inches	5
Overall Diam	eter:
0.107 inches	
Joint Electro	nic Device Engineering Council/jedec/case Outline Designation:
Do-7	
Mounting Me	ethod:
Terminal	
Features Pro	vided:
Hermetically s	sealed case
Semiconduc	
Silicon	
Voltage Ratir	ng In Volts Per Characteristic:
26.2 regulate	or voltage
Current Ratir	ng Per Characteristic:
50.00 microar	mperes source cutoff current of standard range
Power Rating	g Per Characteristic:
400.0 milliwat	ts small-signal input power, common-collector preset
Maximum Op	perating Tempurature Per Measurement Point:
70.0 degrees	celsius ambient air
Terminal Typ	be And Quantity:
2 uninsulated	wire lead
Shelf Life:	
N/a	
Unit Of Meas	sure:
Demilitarizat	ion:
No	
Fiig:	
A110a0	